

A Silicon Vertex Detector with Timing for the Upgrade II of LHCb



**23rd International Workshop on Radiation Imaging
Detectors**

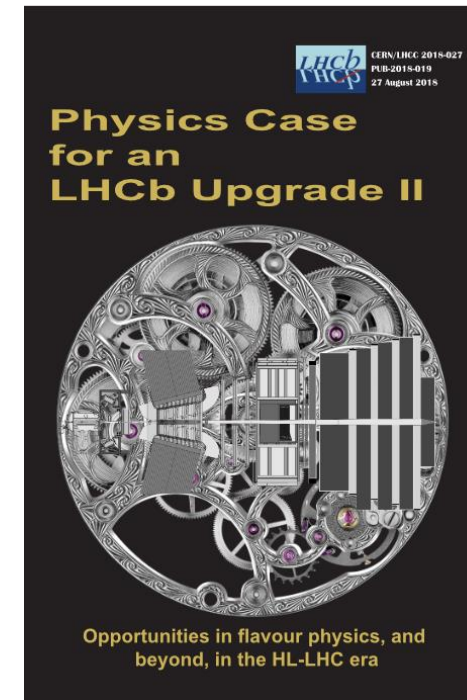
Jakob Haimberger on behalf
of the LHCb VELO group

Motivation

LHCb detector is fully equipped in the forward region, precision measurements of decays of b and c hadrons

Future Goals:

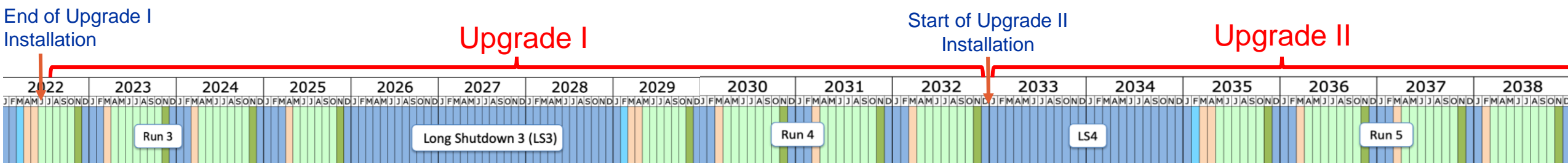
- Bigger data samples to study **rare decays** and **improve uncertainty** for existing ones
- **Extended physics case** in flavor physics and beyond



Upgrade II physics case

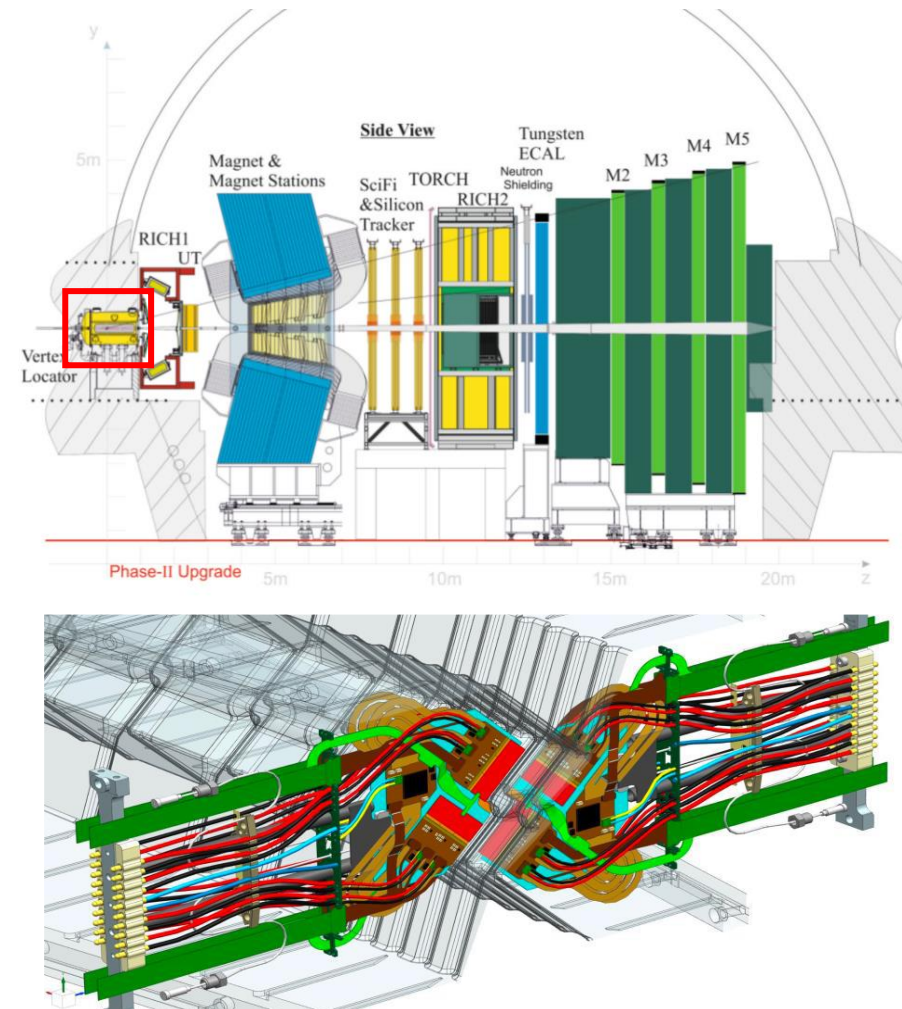


Upgrade II TDR



VERtexas LOcator (VELO) Upgrade I

- **VELO**: silicon tracker close to the collision point
- Need to distinguish between primary and secondary vertices → **as close as possible to beam line (5.1 mm)**
- Previous detector readout limited to 1MHz → limitation for hadronic modes when increasing luminosity
- Upgrade I readout: **40MHz** to fully exploit the factor 5 increase in instantaneous luminosity



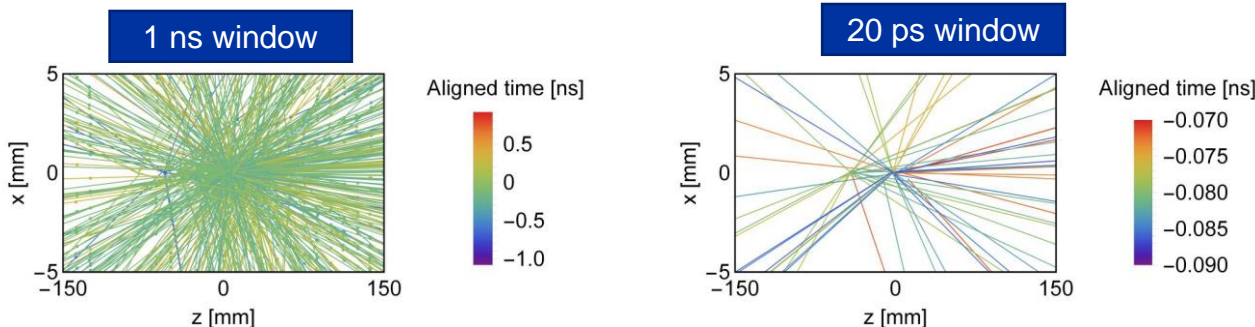
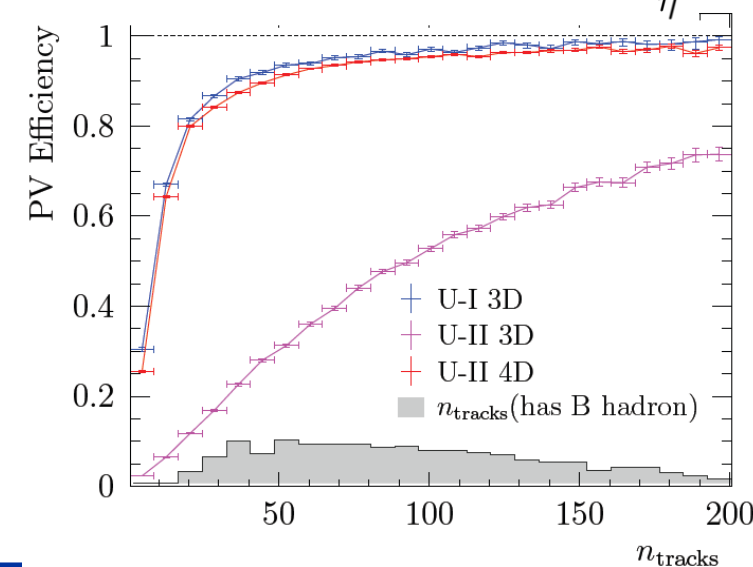
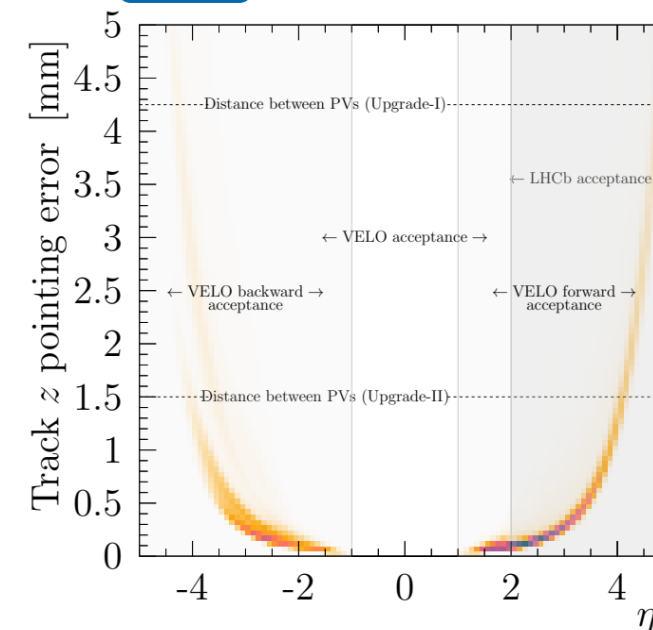
Upgrade II

- Make use of HL-LHC Upgrade:
 - **7.5** x Upgrade I instantaneous luminosity
 - **6** x Upgrade I integrated luminosity
- Similar precision compared to Upgrade I to achieve excellent physic performance
- Main challenges:
 - Increased non uniform **radiation damage**
 - Higher **data rates**
- Open R&D paths:
 - Introduction of **Timing**
 - Different **layout scenarios**
 - New **Sensor** and **ASIC technologies**
 - **Material budget reduction**

	Run1 & 2	Upgrade I	Upgrade II
Inst. Luminosity [cm ⁻² s ⁻¹]	~4 x 10 ³²	~2 x 10 ³³	~1.5 x 10 ³⁴
Luminosity / year [fb ⁻¹]	2	7	50
Collisions per bunch crossing	1.8	5.5	42
Max Integ. Fluence [MeV _{neq} / cm ²]	4.3x10 ¹⁴	8x10 ¹⁵	6x10 ¹⁶
Readout rate / ASIC [10 ⁶ hits/s]		600	4500

The importance of timing

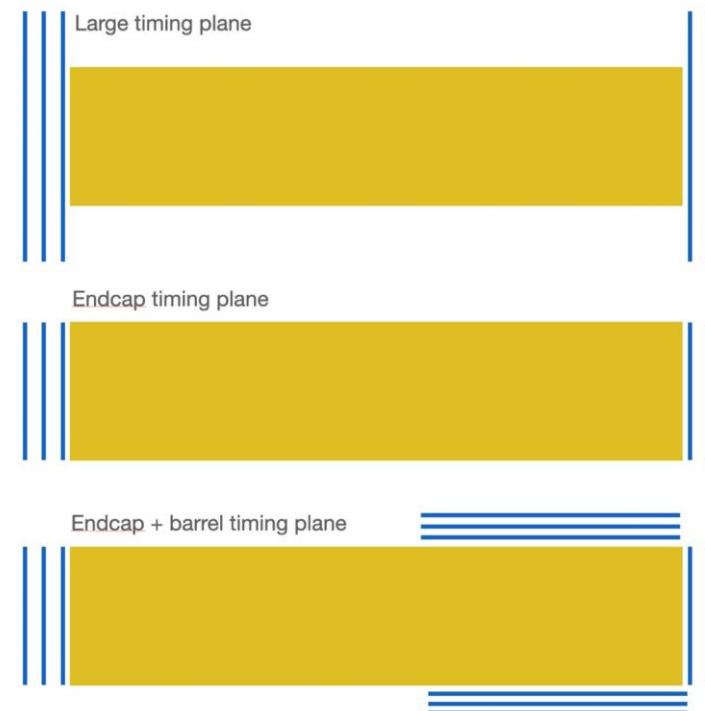
- Higher pileup leads to distance between primary vertices close to detector resolution
- Substantial decrease in primary vertex (PV) reconstruction efficiency
- Spread of PVs (RMS) in time ~ 180 ps
- If tracks can be separated in time, we can recover the lost reconstruction efficiency
- Around **20 ps per track** need to ensure same reconstruction efficiency as Upgrade I



Timing Options 1

Timing Planes:

- At least **three layers** need for outlier rejection
- Far away from interaction point → **less radiation**
- Single measurement needs at least **25 ps resolution**
- **Dispersion** due to different particle momenta
- Three options considered:
 - **Large timing planes**
 - **Endcap planes**
 - **Endcap + barrel in forward direction**



	Upgrade I	Large Planes	Endcaps	Endcaps + Barrel
Covered range	$2 \leq \eta \leq 5$	$2 \leq \eta \leq 5$	$2.8 \leq \eta \leq 5$	$2 \leq \eta \leq 5$
Additional area [m²]	0.1	0.25	0.05	0.4

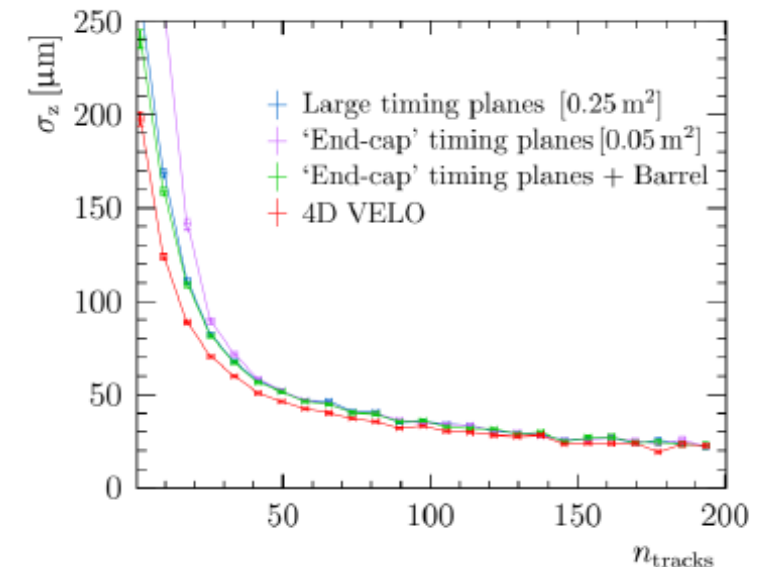
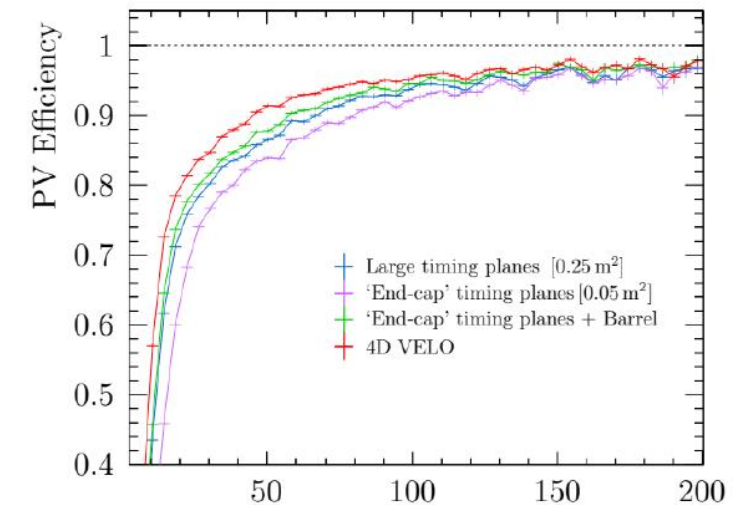
Timing Options 2

4D Tracking

- Single measurement needs at least **50 ps resolution**
- **Better efficiency** in vertex reconstruction and pattern recognition
- Timing needed even in high irradiated region

4D Tracking preferable over dedicated timing planes:

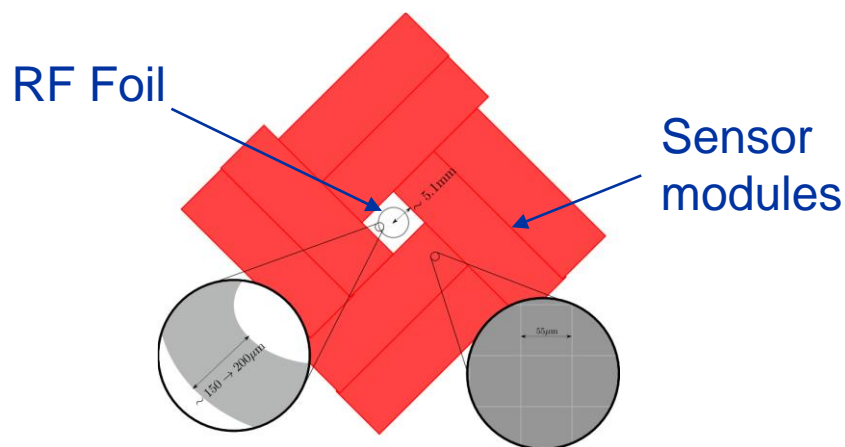
- **Lower cost** due to:
 - No additional sensor area
 - No different ASIC & sensors needed
- **Better reconstruction performance**
 - Better PV efficiency
 - Better PV resolution



Detector layout scenarios for Upgrade II

Scenario A (S_A)

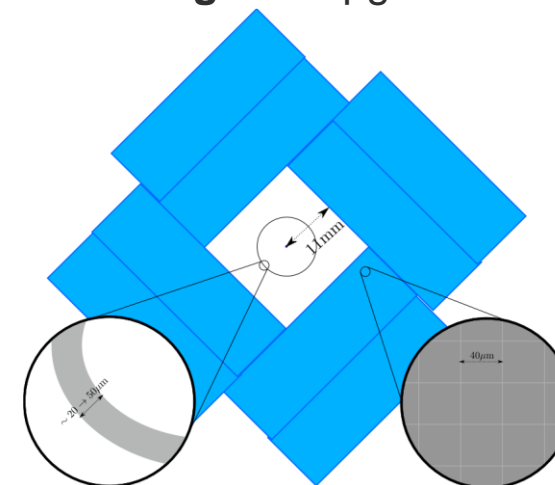
- Distance closest pixel to beamline: **5.1 mm**
- **~9 times higher hit rate (350kHz)** than the VELO Upgrade I
- Either highly **radiation hard sensors /ASIC** or frequent **replacement**
- **6 x radiation damage** as Upgrade I



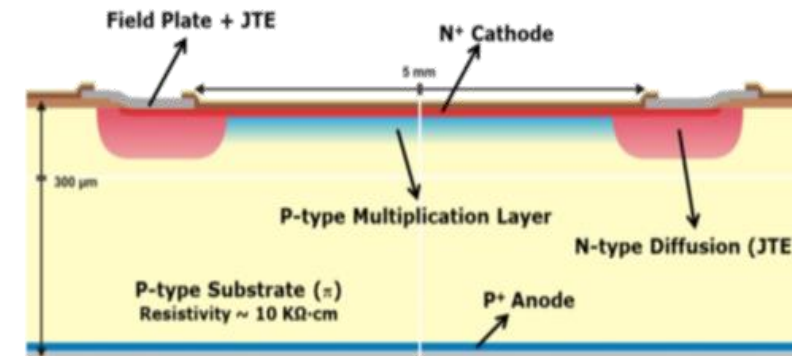
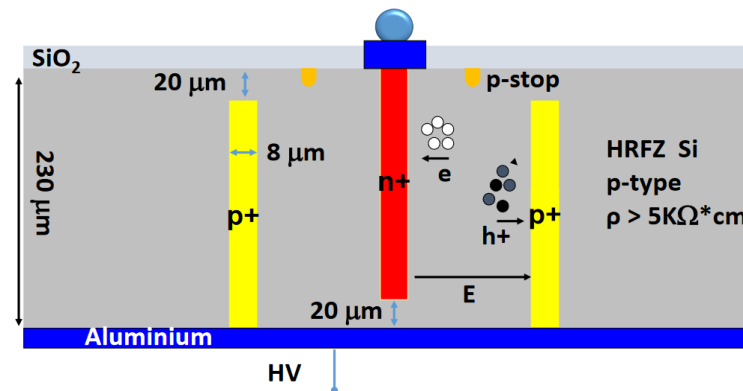
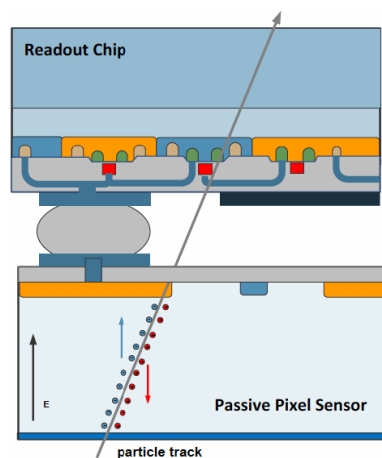
Sketch of a Scenario A using the current sensor modules

Scenario B (S_B)

- Distance closest pixel to beamline: **12.5 mm**
- **Same hit rate** as Upgrade I (40kHz)
- Better hit resolution needed \rightarrow **pixel size $< 42 \mu\text{m}$**
- **Material budget** needs to be reduced before the second measured point
- **Same radiation damage** as Upgrade I



Sensor technology



Planar Sensors:

Performance depends on thickness.
Thin sensors preferable in high irradiation environments.

- 👍 Short collection time
- 👍 Uniform weighting field
- 👎 Low signal to noise ratio

3D Sensors:

Decoupling of charge generation distance and drift distance

- 👍 Timing depended on pixel size
- 👍 Signal proportional to thickness
- 👍 Good radiation hardness
- 👎 Field non-uniformities increase with decreasing pixel size

LGADs:

- 👍 Internal Gain → high signal to noise ratio
- 👍 Good timing performance due to short high field region
- 👎 After $2 \times 10^{15} \text{ MeV}_{\text{neq}} / \text{cm}^2$ loss of gain due to acceptor removal
- 👎 non-uniform irradiation → different gain
- 👎 Segmentation problems at small sizes

ASIC requirements

- In both scenarios the ASIC size is independent from the pixel size:
 - **S_A**: Pixel matrix of 256x256
 - **S_B**: Pixel matrix of 335x335
- Listed hit rate assumes a **cluster size** of **2** and **peak rate** of **1.5** times the listed value
- Hit pile up should be kept below 1%:
 - **S_A**: mean time between hits 2.9 μs → 29ns discharge time
 - **S_B**: mean time between hits 25μs → 250ns discharge time
- Data rate calculations assume a **44 bit** per hit

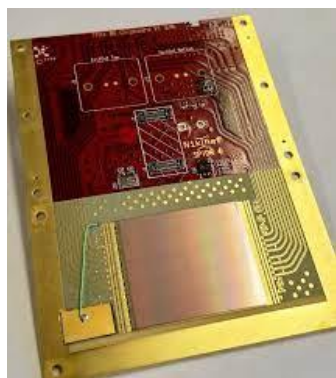
Requirement	scenario <i>S_A</i>	scenario <i>S_B</i>
Pixel pitch [μm]	≤ 55	≤ 42
Lifetime fluence [1×10^{16} 1 MeV n_{eq}/cm^2]	> 6	> 1
TID lifetime [MGy]	> 28	> 5
Sensor Timestamp per hit [ps]	≤ 35	≤ 35
ASIC Timestamp per hit [ps]	≤ 35	≤ 35
Hit Efficiency [%]	≥ 99	≥ 99
Power per pixel [μW]	≤ 23	≤ 14
Pixel rate hottest pixel [kHz]	> 350	> 40
Max discharge time [ns]	< 29	< 250
Bandwidth per ASIC of 2 cm ² [Gb/s]	> 250	> 94

ASIC technology

Current: VeloPix developed in collaboration with the Medipix group (130 nm) for Upgrade I

Velopix1:

- 130nm technology
- 10.44 Gbps/cm²
- Total time resolution 25 ns
- Power: <1.5 W/cm²



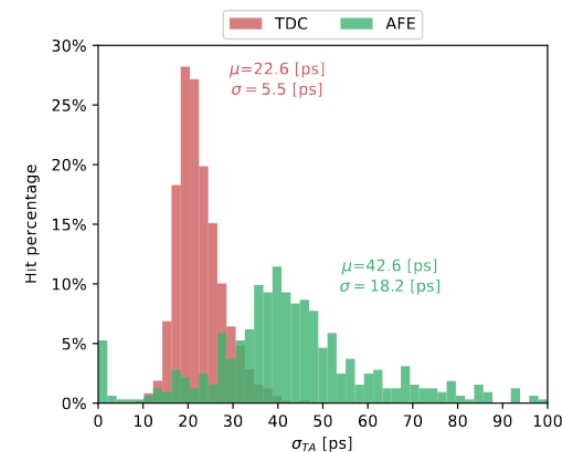
Timepix4 chip

Timespot:

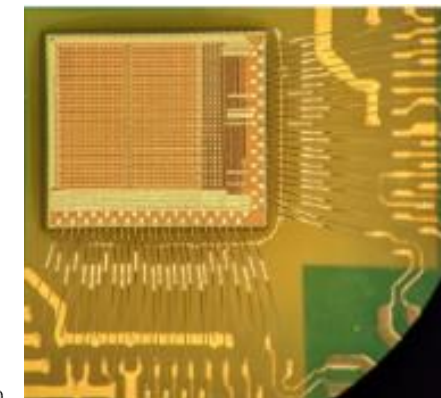
- 28nm technology
- Minimum pixel size < 40 μm
- TDC: ~23 ps resolution
- AFE: ~43 ps resolution
- Power: ~1.2 W/cm²

Timepix4:

- 65nm technology
- 23 Gbps/cm²
- Minimum pixel size 55 μm
- TDC: ~62 ps resolution
- AFE: ~ 70 ps resolution
- Power: <0.5 W/cm²



Timespot1 time resolution



Timespot1 ASIC

PicoPix:

- In development
- Goals:
 - 28nm technology
 - >125 Gbps/cm²
 - Minimum pixel size 42-55 μm
 - Total time resolution < 30 ps
 - Power: <1.5 W/cm²

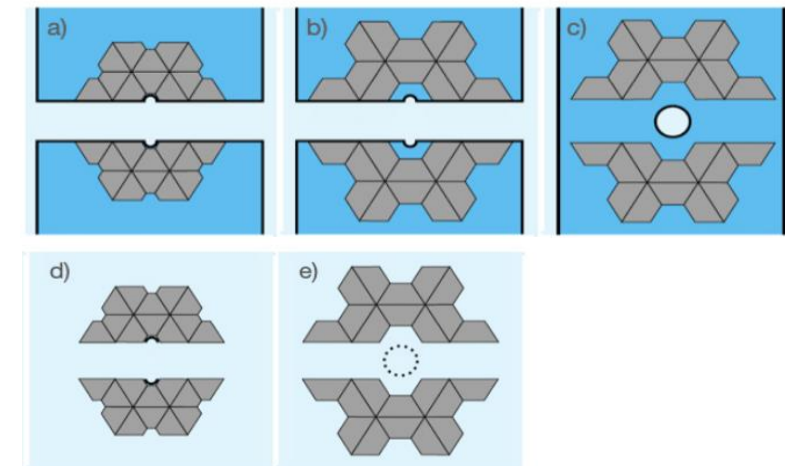
VeloPix II Precursors

RF-Shield

- Conducts **beam mirror current** to avoid wake field excitation
- Shield the detector electronics from **RF pickup**
- Separation between **primary LHC vacuum** and the **secondary detector vacuum** (10 mbar pressure difference)
- Current **corrugated foil** only viable for S_A , as a reduction from 180 to 20 μm thickness needed for S_B not possible
- New **cylindrical shield** options considered:
 - 2-piece movable foil with secondary vacuum for S_A (a) and S_B (b)
 - Single piece fixed foil secondary detector vacuum for S_B (c)
 - 2-piece movable foil without secondary vacuum for S_B (d)
 - Wire frame to conduct beam current and without secondary vacuum for S_B (e)



Upgrade I RF-foil



■ Secondary Vacuum
■ Primary Vacuum
— RF-Foil / •• RF wire / box material

Possible Upgrade II foil solutions

Summary

Next 2 years of R&D for LHCb Upgrade II :

- **2 layout scenarios:**
 - **S_A** : extreme high radiation tolerance and high data rate
 - **S_B**: higher precision hit resolution and a reduction of material budget
- Precise timing: needed **resolution** of **20 ps**
 - **4D tracking** preferable over separate timing planes due to better performance and lower overall cost
- **Fast timing sensors** needed to achieve necessary **spatial and temporal resolution**
- **Material budget** must be adjusted depending on the scenario
- New **vacuum tank and cooling system** must be adjusted to keep accommodate Upgrade II changes



Backup

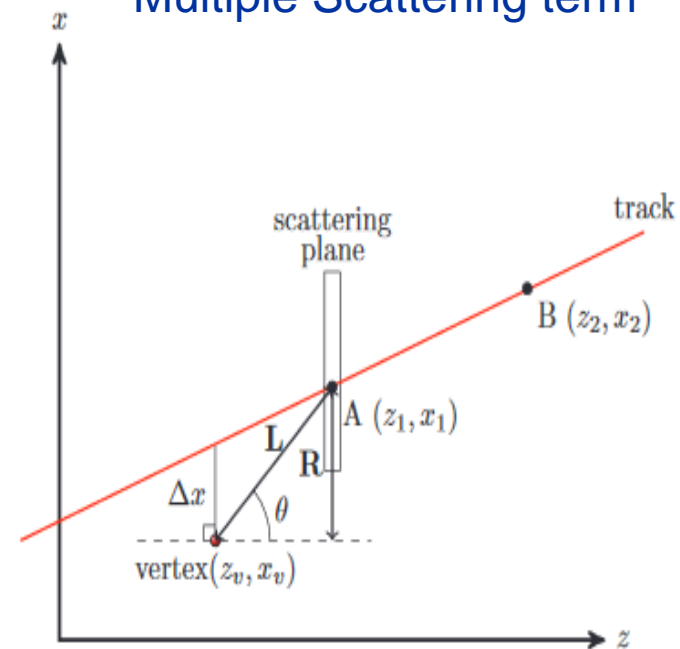
IP-resolution

$$\sigma_{\Delta x}^2 = \frac{\sigma_0^2}{(z_2 - z_1)^2} \left[(z_1 - z_v)^2 + (z_2 - z_v)^2 \right] + \frac{R^2}{p_T^2} \left(\frac{13.6 \text{ MeV}}{c\beta} q \sqrt{\frac{x}{X_0}} [1 + 0.038 \ln(\frac{x}{X_0})] \right)^2$$

Extrapolation term

Multiple Scattering term

- Increasing inner radius implies:
 - Change of layout
 - Change Material Budget (RF-Foil)
 - Change Pixel resolution



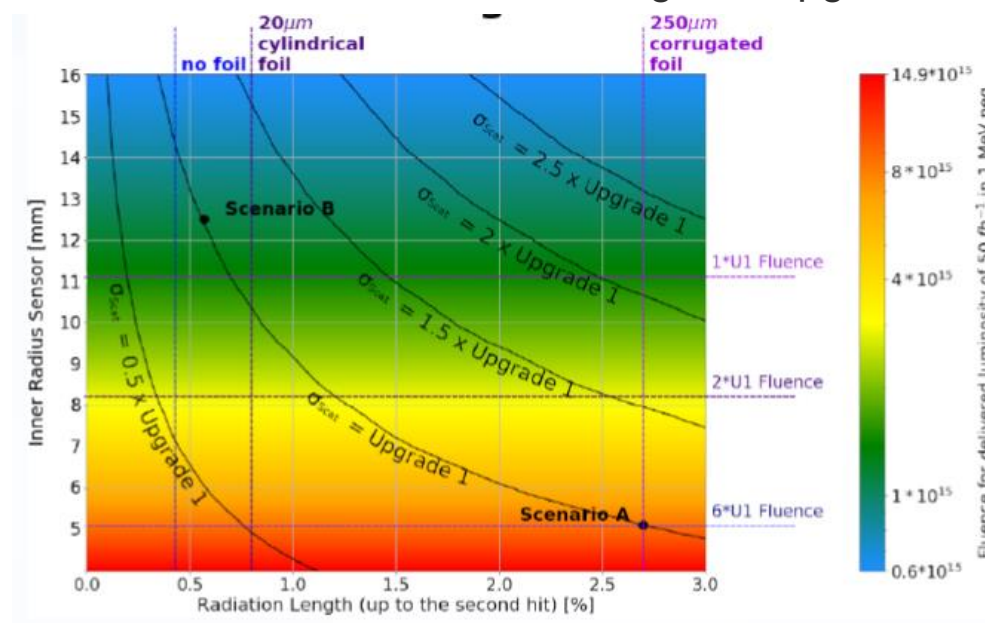
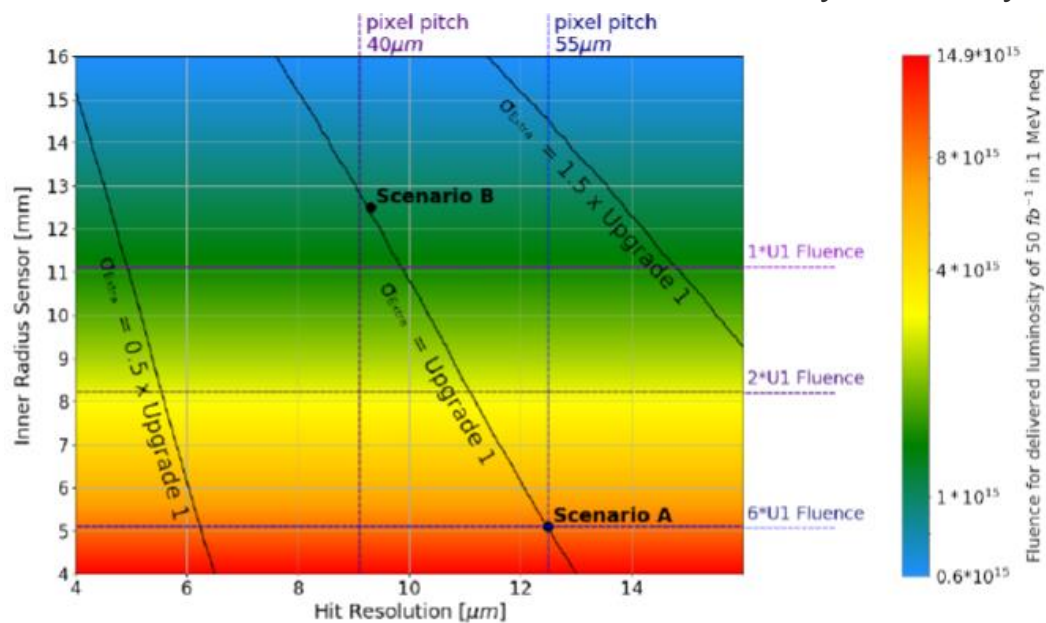
2 Layout Scenarios

Radiation damage and hit rate can be reduced if sensors are **moved away from the beam** (increased inner radius), **at cost of Impact Parameter (IP) resolution** (closest distance between reconstructed track and PV)

IP resolution can be recovered if **hit resolution** is improved **and material budget** is reduced

Two scenarios which would lead to the same IP resolution:

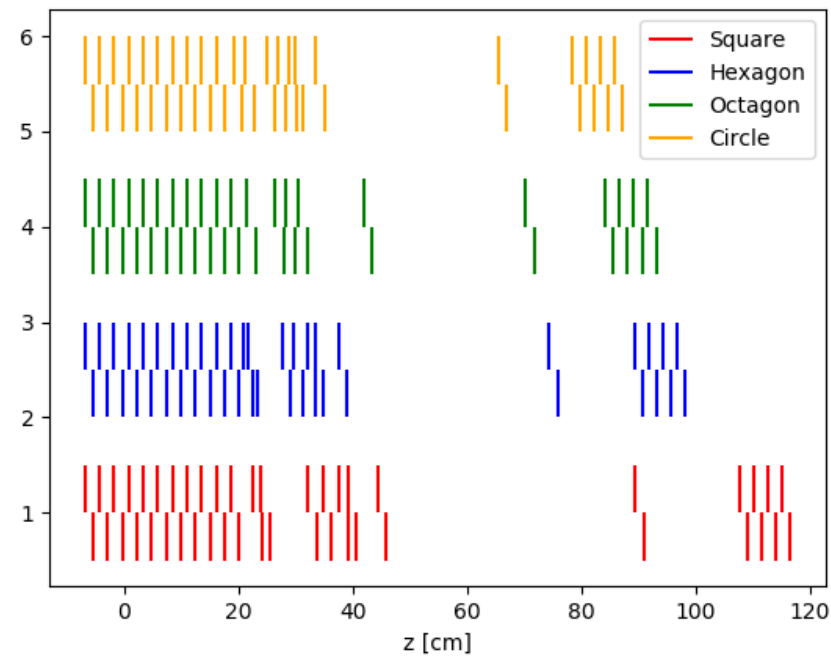
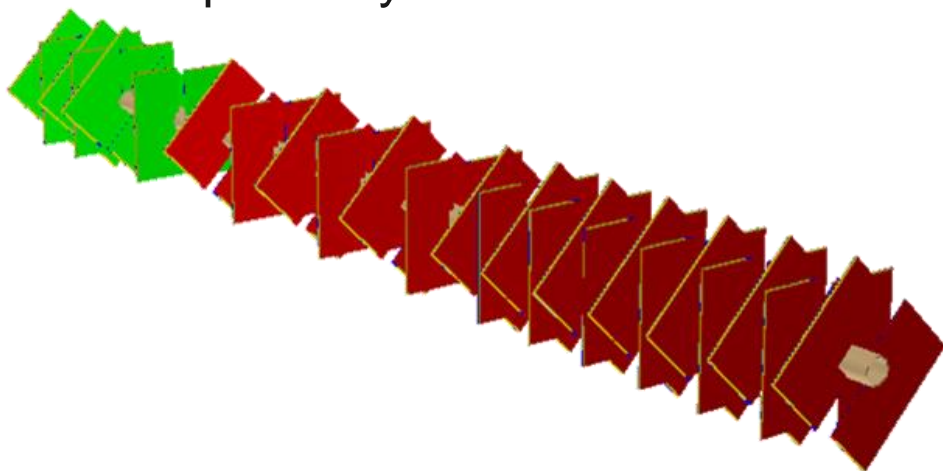
- **Scenario A:** the sensors stay in their Upgrade I position
- **Scenario B:** the sensors are moved away until they receive the same hit rate & radiation damage as Upgrade I



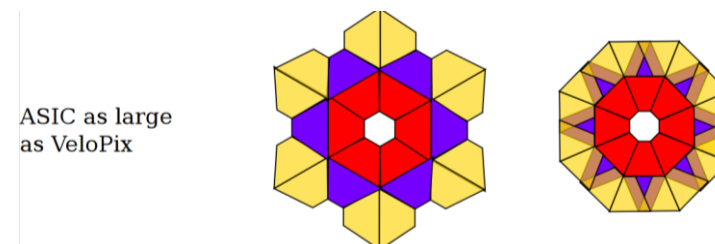
Parametric estimate of IP resolution changes for different inner radii, hit resolutions and material

Detector Length

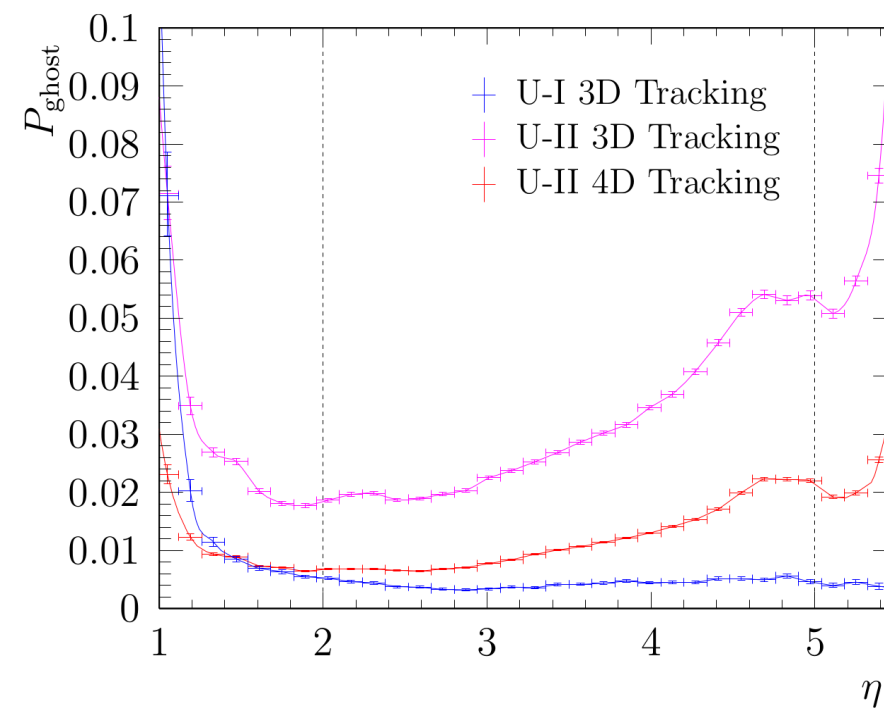
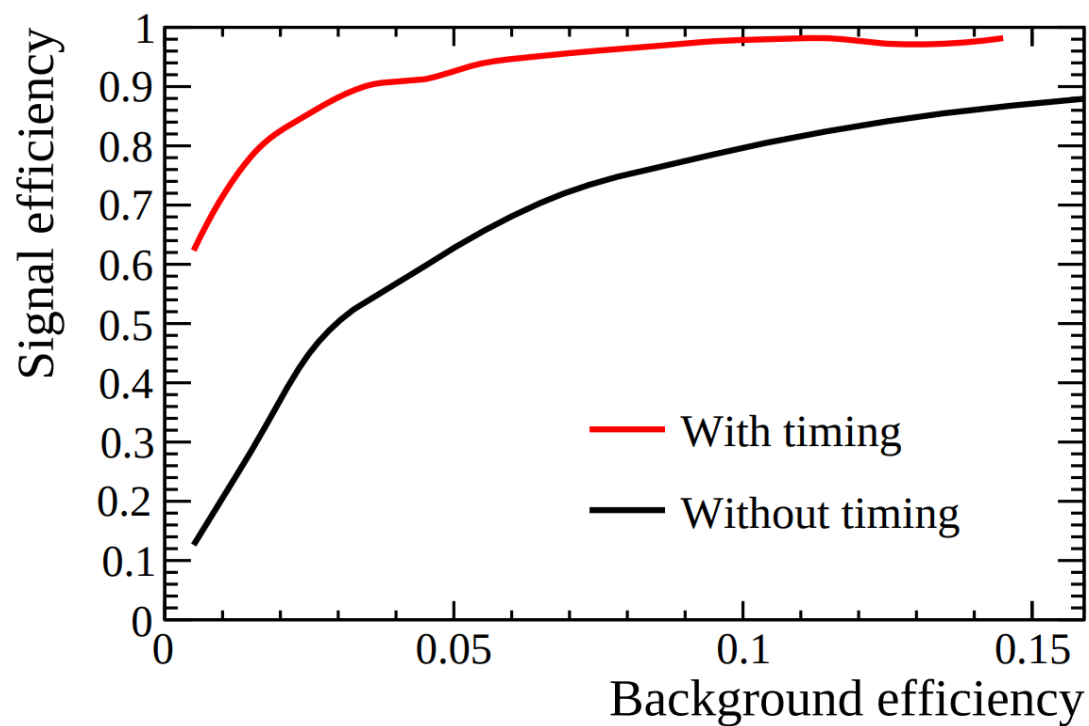
- Detector size depending on value of maximal radial distance of the first hit to the beam (r_{\max})
- r_{\max} depending on shape of inner hole
- The Octagon can also be approximated by using square tiling and rotate every second plane by 45°



Calculated Layouts for different inner hole shapes

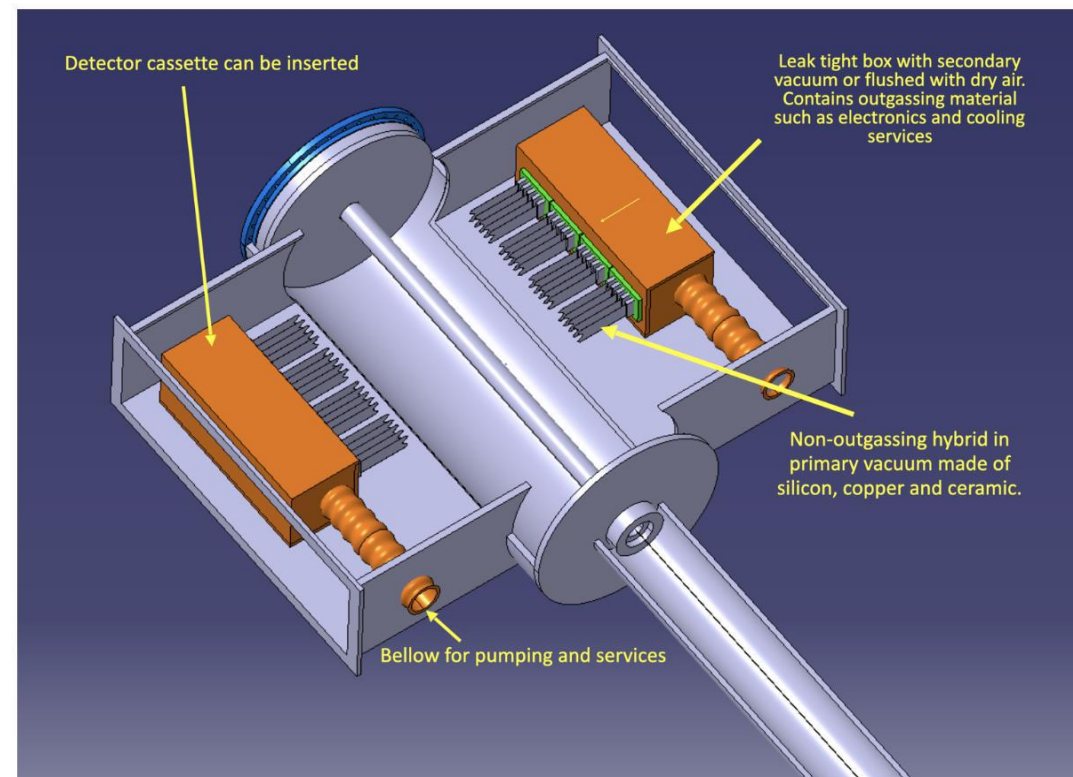


Reconstruction with timing



Vacuum tank

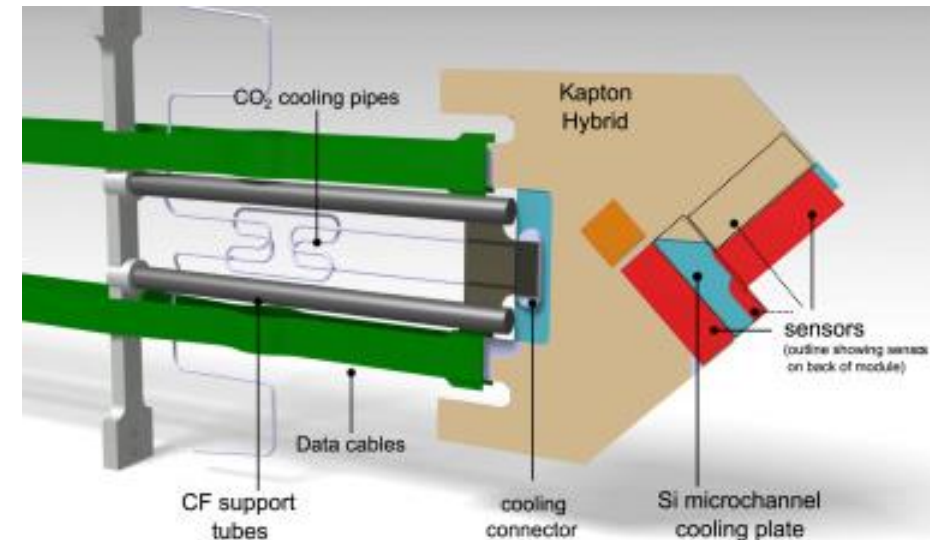
- Needs to be redesigned depending on the scenario
- Needed changes:
 - **Scenario S_A:**
 - Possibility to change the Modules after a certain amount of time
 - **Scenario S_B:**
 - Better vacuum and bakeout resistance if no RF-foil is used
 - Inclusion of a static cylindrical RF-foil



Possible no foil vacuum tank

Cooling

- Cooling is necessary to prevent **thermal runaway** caused by leakage current and to avoid **annealing** of the irradiated sensors.
- Power budget expected to be a least 1.5 W/cm^2 (same as Upgrade I)
- **Upgrade I:**
CO₂ cooling via silicon micro channel plates
- **Upgrade II:**
 - New coolants such as Krypton are needed to allow cooling below -40°C
 - Two phase cooling
 - Alternative substrate solutions involving 3D printing silicon carbide or titanium reduce costs



Upgrade I cooling